10-Bit Low Power Bus Exchange

The ON Semiconductor 74FST3383 is a 10-bit low power bus exchange. The device is CMOS TTL compatible when operating between 4 and 5.5 Volts. The device exhibits extremely low RON and adds nearly zero propagation delay. The device adds no noise or ground bounce to the system.

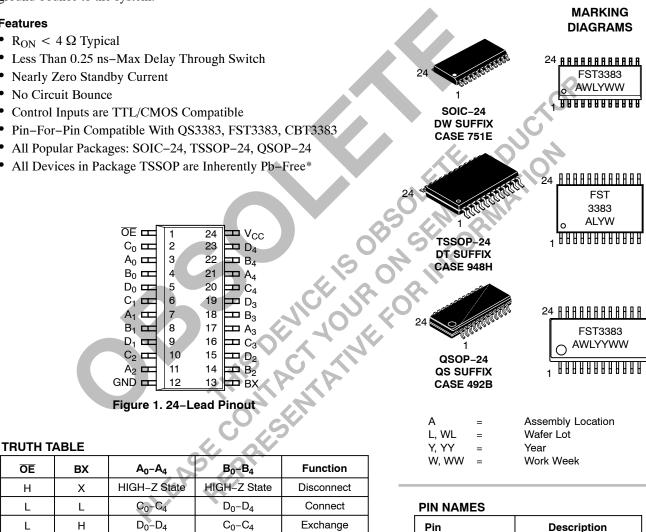
Features

- $R_{ON} < 4 \Omega$ Typical
- Less Than 0.25 ns-Max Delay Through Switch
- Nearly Zero Standby Current
- No Circuit Bounce
- Control Inputs are TTL/CMOS Compatible
- Pin-For-Pin Compatible With QS3383, FST3383, CBT3383
- All Popular Packages: SOIC-24, TSSOP-24, QSOP-24
- All Devices in Package TSSOP are Inherently Pb-Free*



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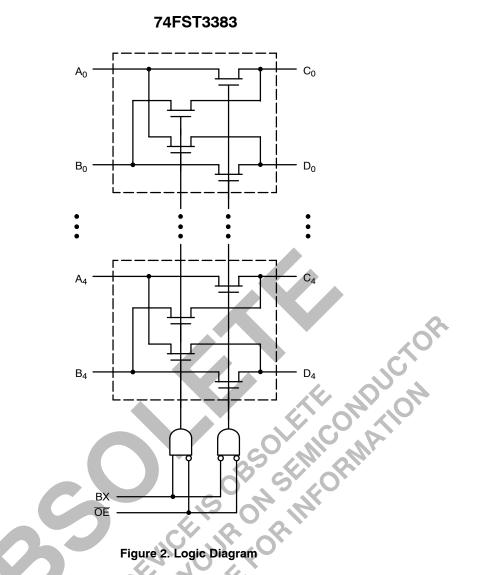
NOTE: H = HIGH Voltage Level, L = LOW Voltage Level, X = Don't Care

PIN NAMES			
Pin Description			
ŌĒ	Bus Switch Enable		
BX	Bus Exchange		
A ₀ -A ₄ , B ₀ -B ₄	Buses A, B		
$C_0 - C_4, D_0 - D_4$	Buses C, D		

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ORDERING INFORMATION

Device Order Number	Package	Shipping [†]
74FST3383DW	SOIC-24	48 Units / Rail
74FST3383DWR2	SOIC-24	2500 Units / Tape & Reel
74FST3383DT	TSSOP-24* (Pb-Free)	96 Units / Rail
74FST3383DTR2	TSSOP-24* (Pb-Free)	2500 Units / Tape & Reel
74FST3383QS	QSOP-24	96 Units / Rail
74FST3383QSR	QSOP-24	2500 Units / Tape & Reel

Figure 2. Logic Diagram

OE

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*This package is inherently Pb-Free.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CC}	DC Supply Voltage	-0.5 to +7.0	V	
VI	DC Input Voltage	-0.5 to +7.0	V	
Vo	DC Output Voltage	-0.5 to +7.0	V	
I _{IK}	DC Input Diode Current $V_{I} < GND$	-50	mA	
I _{OK}	DC Output Diode Current $V_{O} < GND$	-50	mA	
Ι _Ο	DC Output Sink Current	128	mA	
I _{CC}	DC Supply Current per Supply Pin	±100	mA	
I _{GND}	DC Ground Current per Ground Pin	±100	mA	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C	
TJ	Junction Temperature Under Bias	+ 150	°C	
θ_{JA}	Thermal Resistance SOIC TSSOP QSOP	125 170 200	°C/W	
MSL	Moisture Sensitivity	Level 1		
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in		
V _{ESD}	ESD Withstand Voltage Human Body Model (Note 1) Machine Model (Note 2) Charged Device Model (Note 3)	>2000 >200 N/A	V	
I _{Latchup}	Latchup Performance Above V _{CC} and Below GND at 85°C (Note 4)	±500	mA	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the eter Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Tested to EIA/JESD22-A114-A.

2. Tested to EIA/JESD22-A115-A.

З. Tested to JESD22-C101-A.

4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage Operating, Data Retention Only	4.0	5.5	V
VI	Input Voltage (Note 5)	0	5.5	V
Vo	Output Voltage (HIGH or LOW State)	0	5.5	V
T _A	Operating Free-Air Temperature	- 40	+ 85	°C
$\Delta t / \Delta V$		0	DC 5	ns/V

5. Unused control inputs may not be left open. All control inputs must be tied to a high or low logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

			V _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			
Symbol	Parameter	Conditions	(V)	Min	Тур*	Max	Unit
V _{IK}	Clamp Diode Resistance	I _{IN} = -18mA	4.5			-1.2	V
V _{IH}	High-Level Input Voltage		4.0 to 5.5	2.0			V
VIL	Low-Level Input Voltage		4.0 to 5.5			0.8	V
I _I	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	5.5			±1.0	μA
I _{OZ}	OFF-STATE Leakage Current	$0 \le A, B \le V_{CC}$	5.5			±1.0	μA
R _{ON}	Switch On Resistance (Note 6)	$V_{IN} = 0 \text{ V}, \text{ I}_{IN} = 64 \text{ mA}$	4.5		4	7	Ω
		V _{IN} = 0 V, I _{IN} = 30 mA	4.5		4	7	
		V _{IN} = 2.4 V, I _{IN} = 15 mA	4.5		8	15	
		V _{IN} = 2.4 V, I _{IN} = 15 mA	4.0		11	20	
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$	5.5			3	μA
ΔI_{CC}	Increase In I _{CC} per Input	One input at 3.4 V, Other inputs at V_{CC} or GND	5.5			2.5	mA

*Typical values are at $V_{CC} = 5.0$ V and $T_A = 25^{\circ}$ C. 6. Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins. 1 - A

AC ELECTRICAL CHARACTERISTICS

			$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $C_{L} = 50 \text{ pF, RU} = \text{RD} = 500 \Omega$				
			$V_{CC} = 4$.5–5.5 V	V _{CC} =	4.0 V	1
Symbol	Parameter	Conditions	Min	Max	Min	Max	Unit
t _{PHL} , t _{PLH}	Prop Delay Bus to Bus (Note 7)	V _I = OPEN	. N	0.25		0.25	ns
	Prop Delay, BX to An, Bn, Cn or Dn		1.0	5.8		6.5	1
t _{PZH} , t _{PZL}	Output Enable Time, BX to An, Bn, Cn or Dn	$V_{I} = 7 V$ for t_{PZL}	1.0	5.8		6.5	ns
	Output Enable Time, I _{OE} to An, Bn, Cn or Dn	$V_{I} = OPEN$ for t_{PZH}	1.0	5.8		6.5	1
t _{PHZ} , t _{PLZ}	Output Disable Time, BX to An, Bn, Cn or Dn	$V_I = 7 V$ for t_{PLZ}	1.0	5.3		6.2	ns
	Output Disable Time, I _{OE} to An, Bn, Cn or Dn	$V_I = OPEN$ for t_{PHZ}	1.0	5.3		6.2	

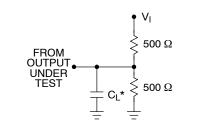
7. This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

CAPACITANCE (Note 8)

Symbol	Parameter	Conditions	Тур	Мах	Unit
C _{IN}	Control Pin Input Capacitance	V _{CC} = 5.0 V	6		pF
C _{I/O}	Port Input/Output Capacitance	$V_{CC}, \overline{OE} = 5.0 V$	13		pF

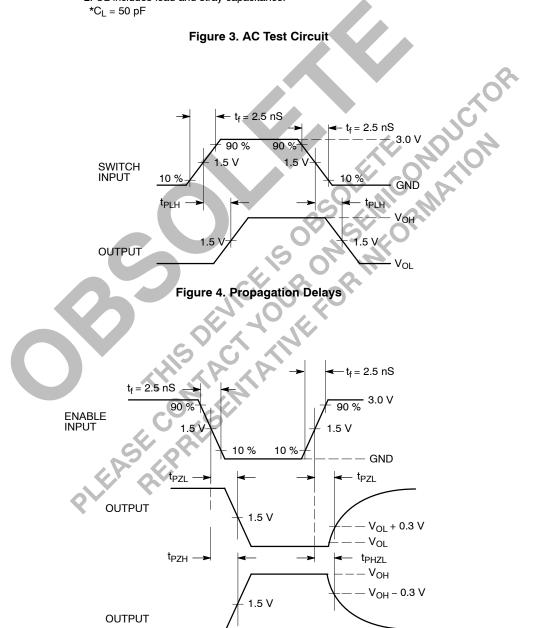
8. $T_A = +25^{\circ}C$, f = 1 MHz, Capacitance is characterized but not tested.

AC Loading and Waveforms



NOTES:

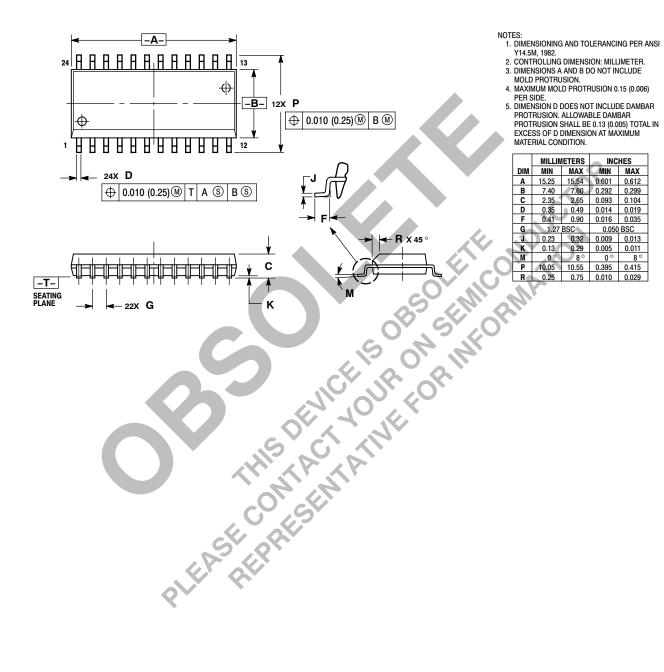
Input driven by 50 Ω source terminated in 50 Ω.
CL includes load and stray capacitance.





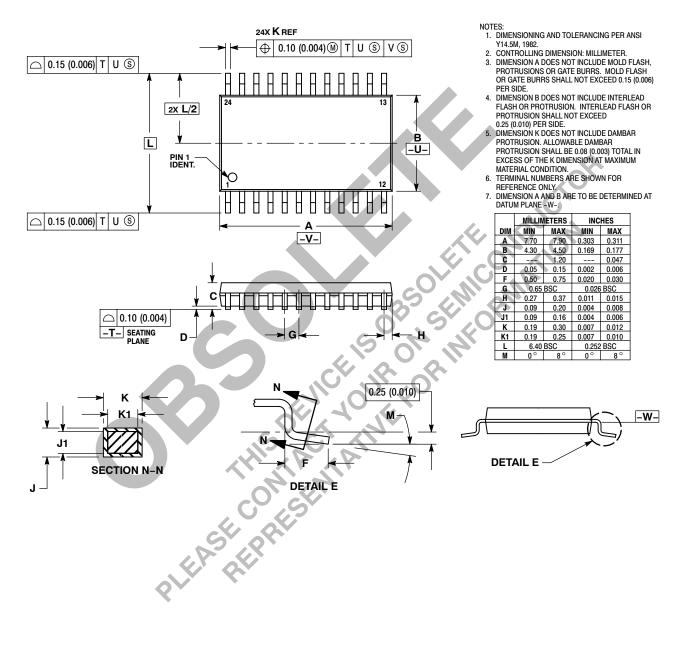
PACKAGE DIMENSIONS

SOIC-24 D SUFFIX CASE 751E-04 ISSUE E

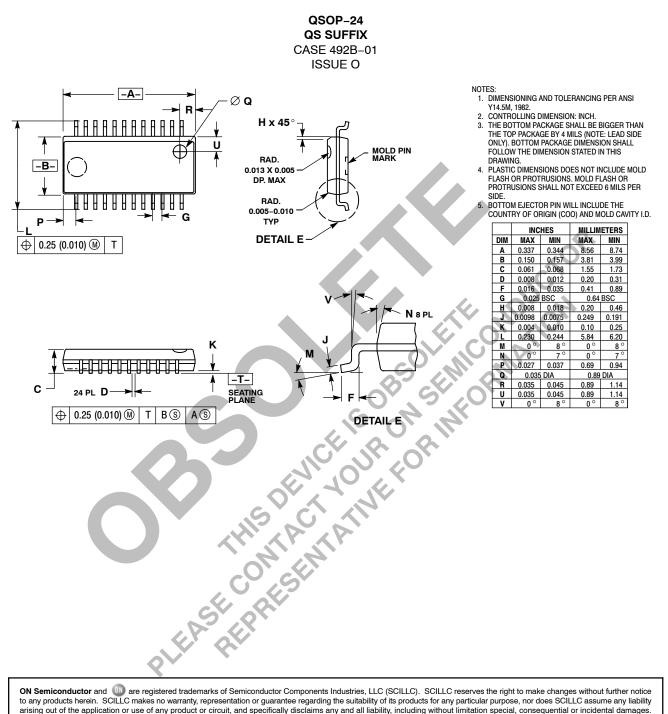


PACKAGE DIMENSIONS

TSSOP-24 DT SUFFIX CASE 948H-01 ISSUE A



PACKAGE DIMENSIONS



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